

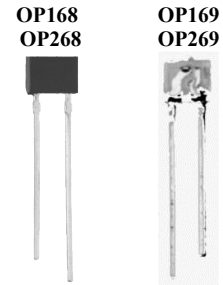
Plastic Infrared Emitting Diode

OP168F, OP169, OP268F, OP269 Series



Features:

- Flat lens for wide radiation angle (OP168, OP268)
- Integral lens for narrow beam angle (OP169, OP269)
- Easily stackable on 0.100" (2.54 mm) hole centers
- Mechanically and spectrally matched to other OPTEK devices



Description:

Each diode in this series is molded into an end-looking plastic package. The package for all **OP168F** and **OP268F** devices is black, whereas the package for all **OP169** and **OP269** packages is clear. **OP168F** and **OP169** devices are GaAs. **OP268F** and **OP269** devices are GaAlAs.

Due to their small size, all diodes in this series offer considerable design flexibility.

The OP168F and OP268F series are mechanically and spectrally matched to the OP508F series phototransistor and the OP538F series photodarlingtons. The OP169 and OP269 series are mechanically and spectrally matched to the OP509 series phototransistors.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

For custom screening contact your OPTEK representative.

Applications:

- Space-limited applications
- Excellent design flexibility
- PCBoard mounted slotted switch
- PCBoard interrupter

| Ordering Information | | | |
|----------------------|---------------------|------------------|-------------|
| Part Number | LED Peak Wavelength | Total Beam Angle | Lead Length |
| OP168FA | 935 nm | 104° | 0.50" |
| OP168FB | | | |
| OP169B | 935 nm | 18° | |
| OP169C | | | |
| OP268FA | 890 nm | 104° | |
| OP268FB | | | |
| OP268FC | | | |
| OP269A | 890 nm | 18° | |



RoHS

General Note

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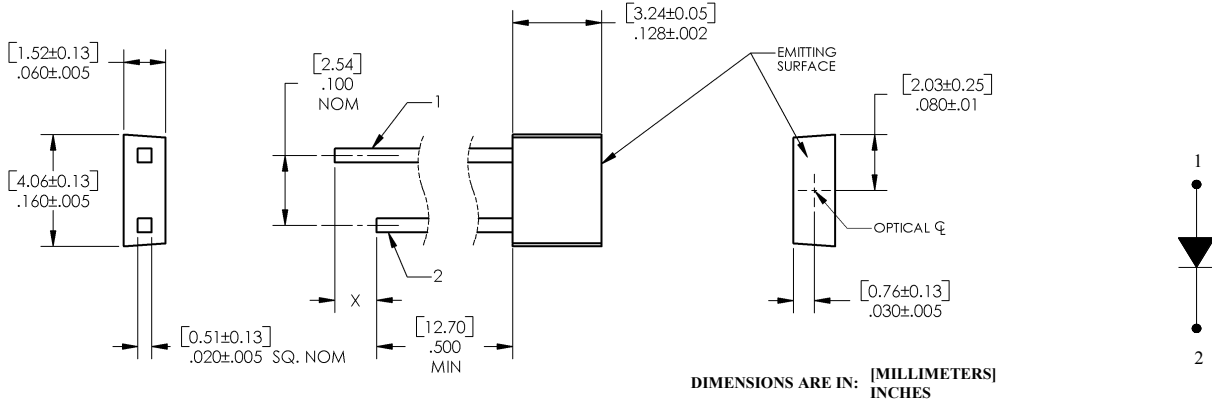
OPTEK Technology, Inc.
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
www.optekinc.com | www.ttelectronics.com

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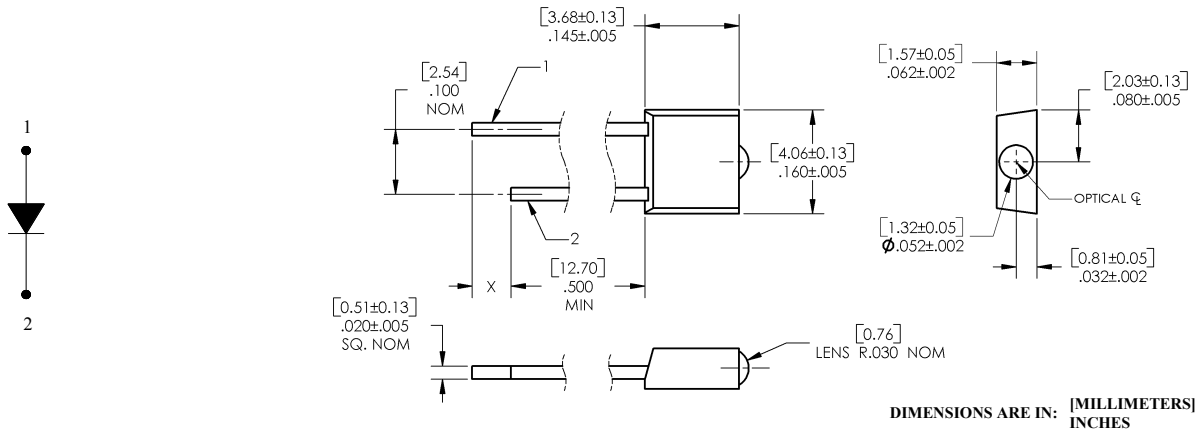


OP168F (B, C), OP268F (A)



| Pin # | LED |
|-------|--------------------------|
| | X=0.060" (1.5 mm) |
| 1 | Anode |
| 2 | Cathode |

OP169 (A, B, C), OP269 (A, B, C)



| Pin # | LED |
|-------|--------------------------|
| | X=0.060" (1.5 mm) |
| 1 | Anode |
| 2 | Cathode |

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Electrical Specifications

| Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted) | |
|--|---|
| Storage and Operating Temperature Range | -40°C to $+100^\circ\text{C}$ |
| Reverse Voltage | 2.0 V |
| Continuous Forward Current | 50 mA |
| Peak Forward Current (1 μs pulse width, 300 pps) OP168, OP169, OP268, OP269 (A) | 3.0 A |
| Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron] ⁽¹⁾ | 260 $^\circ\text{C}$ |
| Power Dissipation ⁽²⁾ | 100 mW |

| Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted) | | | | | | |
|---|-----------------------------|------|-----|------|--------------------|--|
| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| Input Diode | | | | | | |
| $E_{E(APT)}^{(3)}$ | Apertured Radiant Incidence | | | | | $I_F = 20\text{ mA}$ Aperture = .081" dia. Distance = .400" from tip of lens to aperture surface |
| | OP168FA | 0.48 | - | 0.73 | mW/cm ² | |
| | OP168FB | 0.43 | - | - | | |
| | OP169B | 0.11 | - | 0.22 | | |
| | OP169C | 0.03 | - | - | | |
| | OP268FA | 0.64 | - | - | | |
| | OP268FB | 0.45 | - | 0.99 | | |
| OP268FC | 0.36 | - | - | | | |
| | OP269A | 0.58 | - | - | | |
| V_F | Forward Voltage | | | | V | $I_F = 20\text{ mA}$ |
| | OP168, OP169 | - | - | 1.40 | | |
| | OP268, OP269 | - | - | 1.50 | | |
| I_R | Reverse Current | | | | μA | $V_R = 2.0\text{ V}$ |
| | OP168, OP169, OP268, OP269 | - | - | 100 | | |
| λ_P | Wavelength at Peak Emission | | | | nm | $I_F = 20\text{ mA}$ |
| | OP168, OP169 | - | 935 | - | | |
| | OP268, OP269 | - | 890 | - | | |

Notes:

1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to the leads when soldering.
2. Derate linearly 1.33 mW/ $^\circ\text{C}$ above 25 $^\circ\text{C}$.
3. For OP168 (FB, FC) and OP268 (FA, FB, FC), $E_{E(APT)}$ is a measurement of the average apertured radiant energy incident upon a sensing area 0.081" (2.06 mm) in diameter perpendicular to and centered on the mechanical axis of the lens and 0.400" (10.16 mm) from the measurement surface. For OP169 (B, C) and OP269 (A), $E_{E(APT)}$ is a measurement of the average apertured radiant energy incident upon a sensing area 0.180" (4.57 mm) in diameter perpendicular to and centered on the mechanical axis of the lens and 0.653" (16.6 mm) from the lens tip. NOTE: $E_{E(APT)}$ is a measurement of the *average* radiant intensity within the cone formed by the above conditions. $E_{E(APT)}$ is not necessarily uniform within the measured area.

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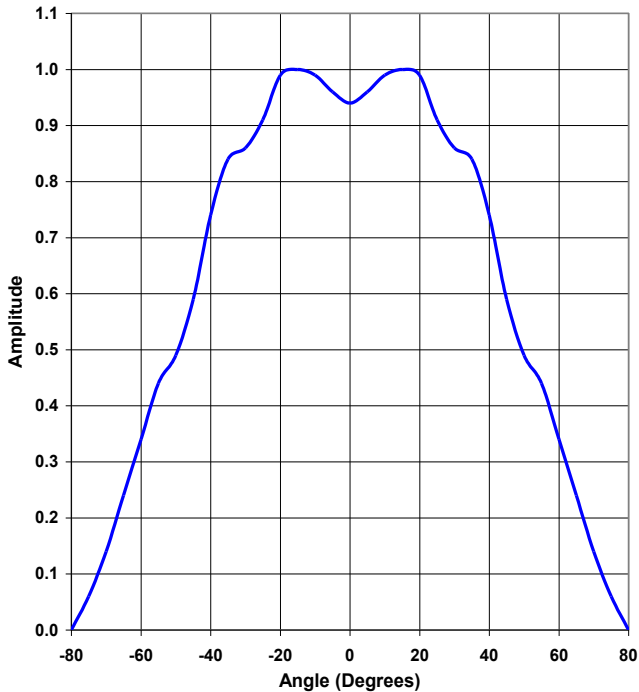
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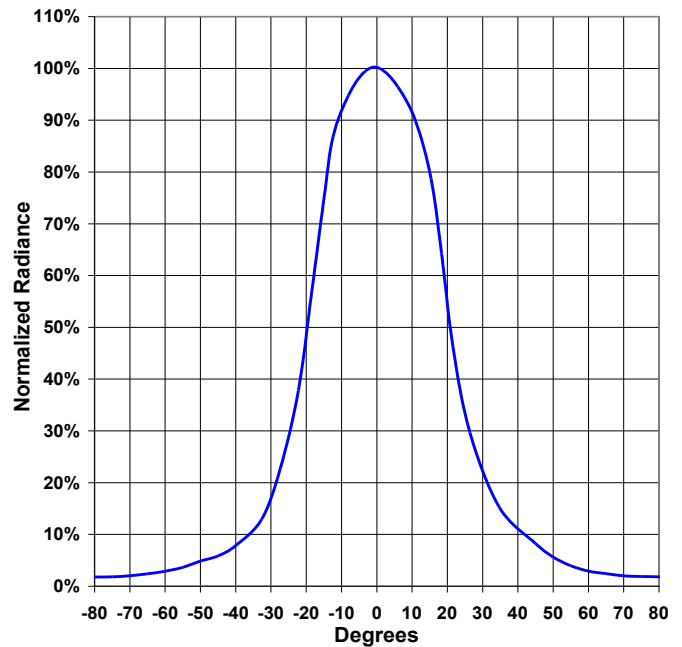
Electrical Characteristics (T_A = 25° C unless otherwise noted— for reference only)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
|------------------------------|--|------------------|----------------------------|------------------|--------|---|
| Input Diode | | | | | | |
| B | Spectral Bandwidth between Half Power Points OP168, OP169 OP268, OP269 | - - | 50 80 | - - | nm | I _F = 10 mA |
| $\Delta\lambda_p / \Delta T$ | Spectral Shift with Temperature OP168, OP169 OP268, OP269 | - - | ± 0.30 ± 0.18 | - - | nm/°C | I _F = Constant |
| θ_{HP} | Emission Angle at Half Power Points OP168 OP169 OP268 OP269 | - - - - | 104° 46° 104° 46° | - - - - | Degree | I _F = 20 mA |
| t _r | Rise Time OP168, OP169 OP268, OP269 | - - - | 1000 500 10 | - - - | ns | I _{F(pk)} =100 mA, PW=10 μ s, D.C.=10% |
| t _f | Fall Time OP168, OP169 OP268, OP269 | - - - | 500 250 10 | - - - | ns | I _{F(pk)} =100 mA, PW=10 μ s, D.C.=10% |

Beam Angle OP168 & OP268 Package



Beam Angle OP169 & OP269 Package



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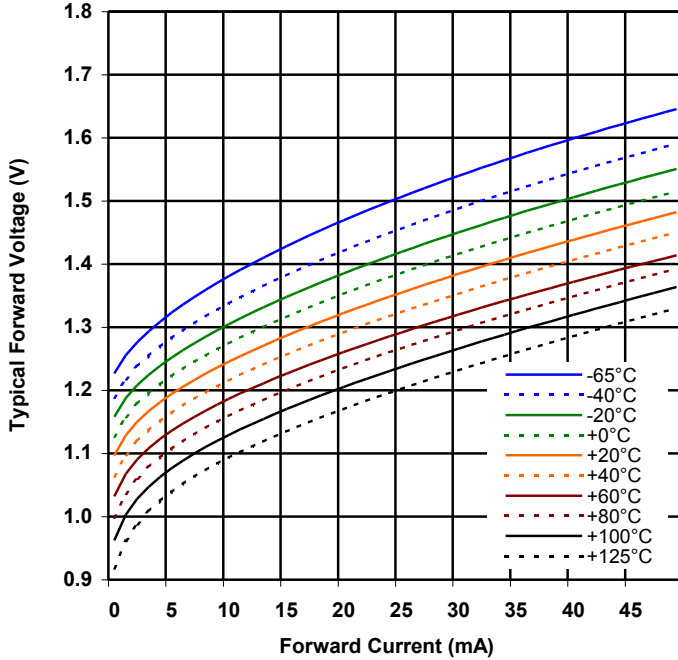
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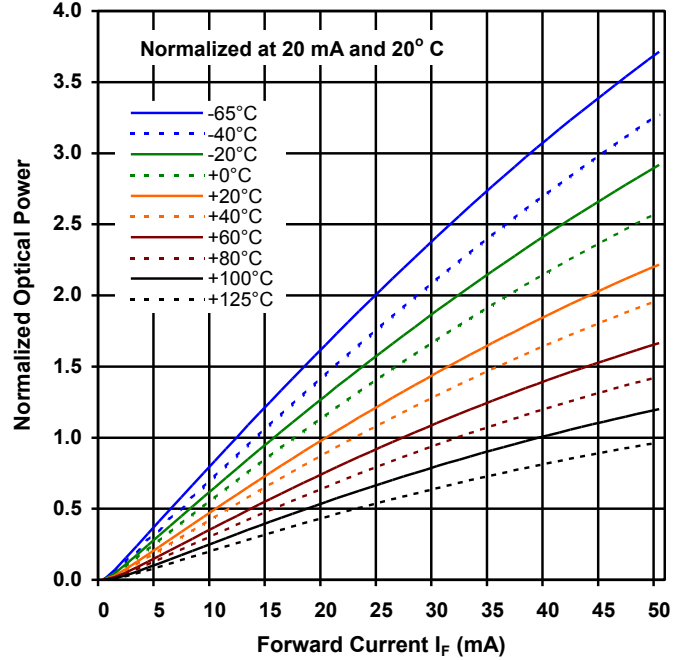
Performance

OP168 (FB, FC), OP169 (B, C)

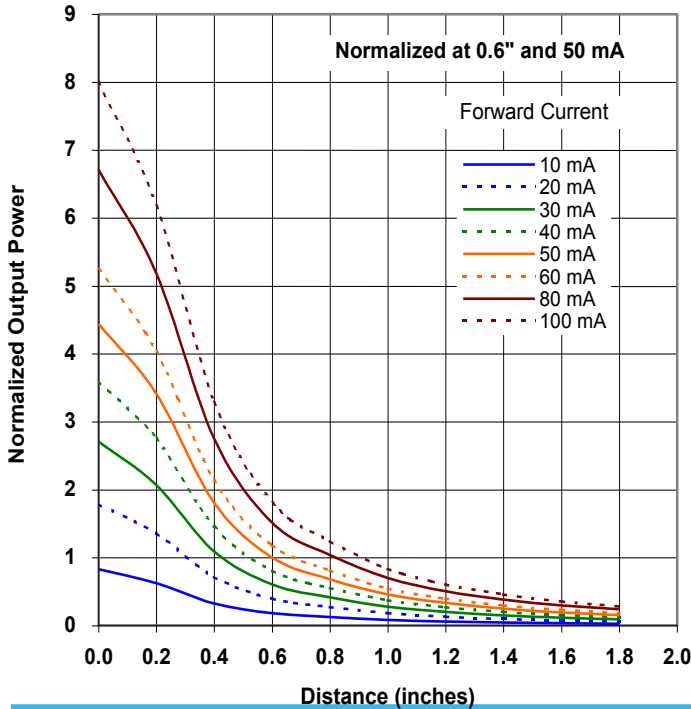
Forward Voltage vs Forward Current vs Temperature



Optical Power vs I_F vs Temp



Distance vs Output Power vs Forward Current



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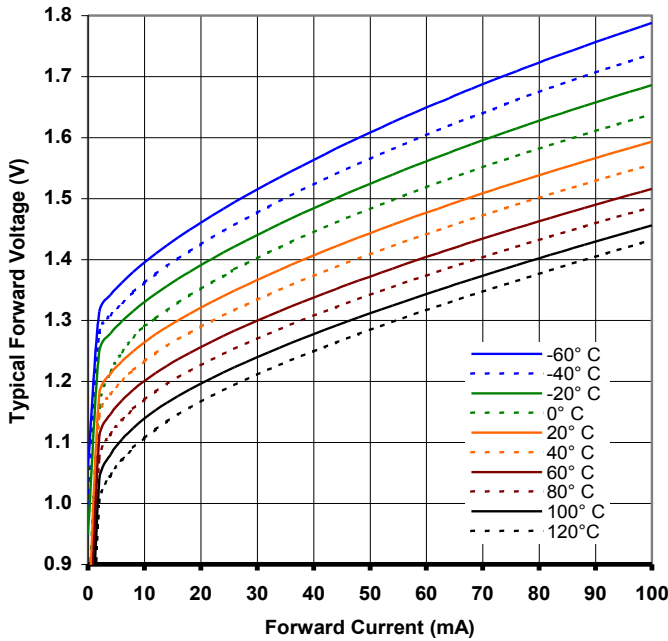
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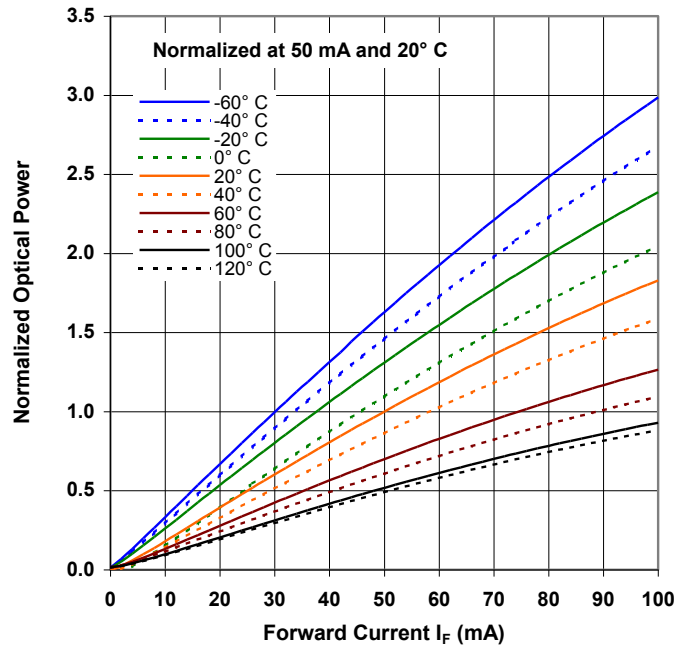
Performance

OP268 (FA, FB, FC), OP269 (A)

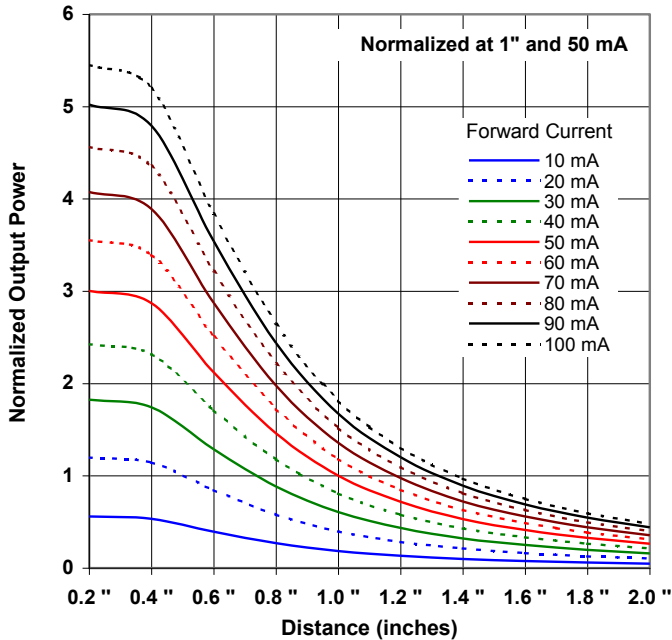
Forward Voltage vs Forward Current vs Temperature



Optical Power vs I_F vs Temperature



Distance vs Output Power vs Forward Current



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Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
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- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
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- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

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- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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